# T1625T-8I

# 57

# Standard 16 A Triac

#### Datasheet – production data

### Features

- Four quadrants
- Trigger current of 25 mA
- Package is RoHS (2002/95/EC) compliant
- Tab insulated, voltage = 2500 V rms
- UL certified (ref. file E81734)

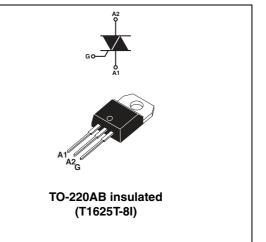
## Applications

- General purpose AC line load switching
- Home appliances:
  - Fan
  - Pump
  - Solenoid
- Lighting
- Heaters
- Inrush current limiting circuits
- Overvoltage crowbar protection circuits

# Description

Available in TO220AB-Ins. (ceramic insulated), the T1625T-8I Triac can be used as on/off or phase angle function controllers in general purpose AC switching.

Provides insulation rated at 2500 V rms (TO-220AB insulated package).



#### Table 1. Device summary

| Order code | Quadrants | Value I <sub>GT</sub> (mA) |
|------------|-----------|----------------------------|
| T1625T-8I  | -    -    | 25                         |
| 110231-01  | IV        | 50                         |

# 1 Characteristics

| Symbol                                 | Parameter  | Value  | Unit                     |             |                  |
|--|--|--|--------------------------|-------------|------------------|
| I                                      |  |  | T <sub>c</sub> = 108 °C  | 16          | ٨                |
| I <sub>T(RMS)</sub>                    | On-state rms current (full sine wave)  | T <sub>c</sub> = 119 °C                          | 12                       | A           |                  |
| 1                                      | Non repetitive surge peak on-state current (full                                   | F = 50 Hz  | t <sub>p</sub> = 20 ms   | 120         | А                |
| I <sub>TSM</sub>                       | cycle, T <sub>j</sub> initial = 25 °C)   | F = 60 Hz  | t <sub>p</sub> = 16.7 ms | 126         | A                |
| l <sup>2</sup> t                       | I <sup>2</sup> t Value for fusing  | -  | t <sub>p</sub> = 10 ms   | 95          | A <sup>2</sup> s |
| V <sub>DRM</sub> ,                     | Ponetitive peak off state voltage, gets open                                       |  | T <sub>j</sub> = 150 °C  | 600         | V                |
| $V_{RRM}$                              | Repetitive peak off-state voltage, gate open                                       | T <sub>j</sub> = 125 °C                          | 800                      | v           |                  |
| V <sub>DSM</sub> ,<br>V <sub>RSM</sub> | Non repetitive surge peak off-state voltage  | je peak off-state voltage t <sub>p</sub> = 10 ms |                          | 900         | V                |
| dl/dt                                  | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$                  |  | F = 100 Hz               | 100         | A/µs             |
| I <sub>GM</sub>                        | Peak gate current  | t <sub>p</sub> = 20 μs                           | T <sub>j</sub> = 150 °C  | 4           | А                |
| P <sub>G(AV)</sub>                     | Average gate power dissipation   |  | T <sub>j</sub> = 150 °C  | 1           | W                |
| T <sub>stg</sub>                       | Storage junction temperature range   |  |                          | -40 to +150 | О°               |
| Тj                                     | Operating junction temperature range   | -40 to +150                                      | Ũ                        |             |                  |
| ΤL                                     | Lead temperature for soldering during 10 s<br>(at 4 mm from case for TO220AB-ins.) |  |                          |             | °C               |
| V <sub>ins</sub><br>(rms)              | Insulation rms voltage, 1 minute, TO220AB ceramic                                  |  | 2500                     | V           |                  |

### Table 2. Absolute maximum rating ( $T_i = 25$ °C, unless otherwise specified)



| Symbol                         | Test conditions   | Quadrant                |            | Value   | Unit |      |
|--------------------------------|---|-------------------------|------------|---------|------|------|
|                                |   |                         | -    -     | MAX.    | 25   |      |
| I <sub>GT</sub> <sup>(1)</sup> |   |                         |            | MAX.    | 50   |      |
| 'GT`′                          | $V_D$ = 12 V, $R_L$ = 30 $\Omega$   |                         | -    -     | MIN.    | 1.25 | mA   |
|                                |   |                         | IV         | MIN.    | 2.50 |      |
| V <sub>GT</sub>                | $V_D$ = 12 V, RL = 30 $\Omega$  |                         | All        | MAX.    | 1.3  | V    |
| V <sub>GD</sub>                | $V_{D}$ = 800 V, $R_{L}$ = 3.3 k $\Omega$ , $T_{j}$ = 125 °C  |                         | All        | MIN.    | 0.2  | V    |
| I <sub>H</sub> <sup>(1)</sup>  | I <sub>T</sub> = 500 mA   |                         |            | MAX.    | 35   | mA   |
|                                |   |                         | I - III-IV | MAX.    | 40   | mA   |
| ۱L                             | $I_{G} = 1.2 I_{GT}$  | II                      | 50         |         |      |      |
| dV/dt <sup>(1)</sup>           | $V_D = 67\% \ x \ 800 \ V \ gate \ open$ $T_j = 125 \ ^{\circ}C$  |                         |            | MIN.    | 500  | V/ue |
| uv/ut V                        | $V_D = 67\% \text{ x } 600 \text{ V gate open}$   | T <sub>j</sub> = 150 °C |            | IVIIIN. | 300  | V/µs |
| (dl/dt)c <sup>(1)</sup>        | $T_j = 125 ^{\circ}\text{C}$  |                         |            | MIN.    | 4    | A/ms |
|                                | $(dV/dt)c = @ 10 V/\mu s$ $T_j = 150 °C$  |                         | 2          |         |      |      |
| (dl/dt)c <sup>(1)</sup>        | $(dV/dt)c = @ 0.1 V/\mu s$ $T_j = 125 °C$ $T_j = 150 °C$  |                         |            | MIN.    | 12   | A/ms |
|                                |   |                         |            | IVIIIN. | 6    |      |
| t <sub>GT</sub>                | gate controlled turn on time $I_{TM}$ = 13 A, $V_D$ = 40 $I_G$ = 100 mA, $dI_G/dt$ = 100 mA/µs, $R_L$ = 30 $\Omega$ | All                     | TYP.       | 2       | μs   |      |

Table 3.Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

1. For both polarities of A2 referenced to A1

#### Table 4.Static characteristics

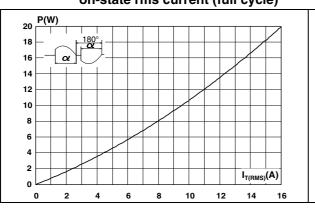
| Symbol                               | Test conditions                                   | Value                   | Unit |      |    |
|--------------------------------------|---|-------------------------|------|------|----|
| V <sub>TM</sub> <sup>(1)</sup>       | I <sub>TM</sub> = 22.6 A, t <sub>p</sub> = 380 μs | T <sub>j</sub> = 25 °C  | MAX. | 1.55 | V  |
| V <sub>to</sub> <sup>(1)</sup>       | Threshold voltage                                 | T <sub>j</sub> = 150 °C | MAX. | 0.85 | V  |
| R <sub>d</sub> <sup>(1)</sup>        | Dynamic resistance                                | T <sub>j</sub> = 150 °C | MAX. | 30   | mΩ |
|                                      | V _ V _ 200 V                                     | T <sub>j</sub> = 25 °C  | MAX. | 5    | μA |
| I <sub>DRM</sub><br>I <sub>RRM</sub> | $V_{\text{DRM}} = V_{\text{RRM}} = 800 \text{ V}$ | T <sub>j</sub> = 125 °C |      | 1    | mA |
|                                      | $V_{DRM} = V_{RRM} = 600 V$                       | T <sub>j</sub> = 150 °C |      | 3.6  | ША |

1. for both polarities of A2 referenced to A1

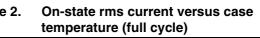
#### Table 5.Thermal resistance

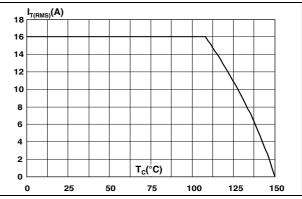
| Symbol               | Parameter             |     | Unit |
|----------------------|-----------------------|-----|------|
| R <sub>th(j-c)</sub> | Junction to case (AC) | 2.1 | °C/W |
| R <sub>th(j-a)</sub> | Junction to ambient   | 60  | °C/W |





# Figure 1. Maximum power dissipation versus Figure 2. on-state rms current (full cycle)





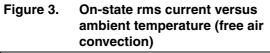


Figure 4. Relative variation of thermal impedance versus pulse duration

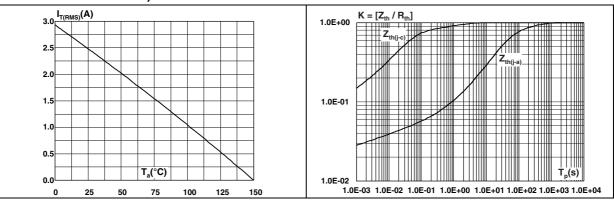
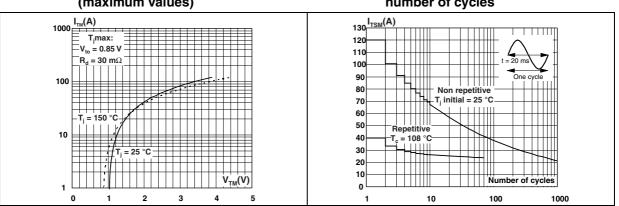


Figure 5. On-state characteristics (maximum values)

Figure 6. Surge peak on-state current versus number of cycles





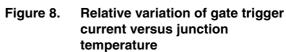
typical values

T<sub>j</sub>(°C)

150

110 130

#### Non repetitive surge peak on-state Figure 7. current and corresponding values of I<sup>2</sup>t



 $I_{GT}[T_j]/I_{GT}[T_j = 25 \ ^{\circ}C]$ 

Q4 I<sub>c</sub>

-10

10

30 50

Q1-Q2

4.0

3.5

3.0

2.5

2.0

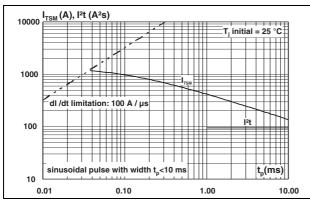
1.5

1.0

0.5

0.0

-50 -30



#### Figure 9. Relative variation of gate trigger voltage versus junction temperature

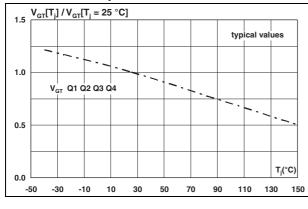
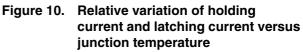
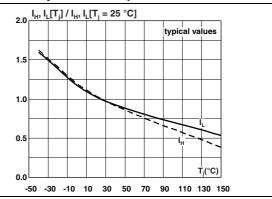


Figure 11. decrease of main current (di/dt)c versus reapplied (dV/dt)c

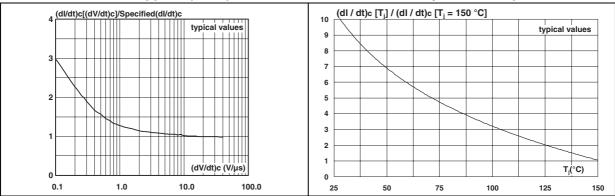


70

90



Relative variation of critical rate of Figure 12. Relative variation of critical rate of decrease of main current (di/dt)c versus junction temperature



| 1.0E+00 | T <sub>j</sub> ; V <sub>DRM</sub> / V <sub>RRM</sub> ] / I <sub>DR</sub>      | M/I <sub>RRM</sub> | <i>.</i> ′ /,   |   |
|---------|---|--------------------|---|---|
| 1.0E-01 | V <sub>DRM</sub> = V <sub>RRI</sub><br>= V <sub>RRM</sub> = 600 V             | w = 800 V          |   |   |
| 1.0E-02 |   |                    |   |   |
| 1.0E-03 |   |                    | T <sub>j</sub> = 125 °C; 800 V];<br>T <sub>j</sub> = 150 °C; 600 V] |   |
| 1.0E-04 | $V_{\text{DRM}} = V_{\text{RRM}} = 400 \text{ V}$ $  \qquad   \qquad  $ 50 75 | 100                | T <sub>j</sub> (°C)   | 0 |

# Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage



# 2 Package information

- Epoxy meets UL94, V0
- Recommended torque value: 0.4 to 0.6 N·m

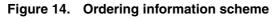
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

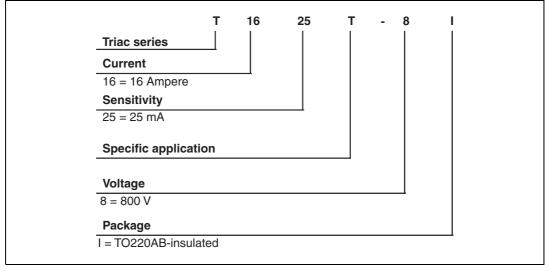
Table 6.TO-220AB (Nins. and ins. 20-up) dimensions

|          |          |    |             |       | Dimer | nsions |       |       |
|----------|----------|----|-------------|-------|-------|--------|-------|-------|
|          |          |    | Millimeters |       |       | Inches |       |       |
|          |          |    | Min.        | Тур.  | Max.  | Min.   | Тур.  | Max.  |
|          |          | А  | 15.20       |       | 15.90 | 0.598  |       | 0.625 |
|          |          | a1 |             | 3.75  |       |        | 0.147 |       |
| ØI       | ba C     | a2 | 13.00       |       | 14.00 | 0.511  |       | 0.551 |
|          |          | В  | 10.00       |       | 10.40 | 0.393  |       | 0.409 |
|          | <b>F</b> | b1 | 0.61        |       | 0.88  | 0.024  |       | 0.034 |
|          |          | b2 | 1.23        |       | 1.32  | 0.048  |       | 0.051 |
| 14 I3 ·  |          | С  | 4.40        |       | 4.60  | 0.173  |       | 0.181 |
|          | c2       | c1 | 0.49        |       | 0.70  | 0.019  |       | 0.027 |
|          |          | c2 | 2.40        |       | 2.72  | 0.094  |       | 0.107 |
| a2       |          | e  | 2.40        |       | 2.70  | 0.094  |       | 0.106 |
|          | M        | F  | 6.20        |       | 6.60  | 0.244  |       | 0.259 |
| <br>e b1 | ← c1     | ØI | 3.75        |       | 3.85  | 0.147  |       | 0.151 |
|          |          | 14 | 15.80       | 16.40 | 16.80 | 0.622  | 0.646 | 0.661 |
|          |          | L  | 2.65        |       | 2.95  | 0.104  |       | 0.116 |
|          |          | 12 | 1.14        |       | 1.70  | 0.044  |       | 0.066 |
|          |          | 13 | 1.14        |       | 1.70  | 0.044  |       | 0.066 |
|          |          | М  |             | 2.60  |       |        | 0.102 |       |



# **3** Ordering information scheme







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# 4 Ordering information

### Table 7. Ordering information

| Order code | Marking   | Package               | Weight | Base qty | Delivery mode |
|------------|-----------|-----------------------|--------|----------|---------------|
| T1625T-8I  | T1625T-8I | TO-220AB<br>insulated | 2.3    | 50       | Tube          |

# 5 Revision history

#### Table 8.Document revision history

| Date        | Revision | Changes                   |  |
|-------------|----------|---------------------------|--|
| 20-Jan-2012 | 1        | First issue.              |  |
| 25-Apr-2012 | 2        | Updated UL certification. |  |



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